CMLSH2-4T

SURFACE MOUNT SILICON TRIPLE ISOLATED LOW V_F SCHOTTKY DIODE



 \bullet Device is $\it Halogen\ Free$ by design



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMLSH2-4T consists of three (3) isolated silicon Schottky diodes, manufactured in an SOT-563 surface mount package. This device is designed for switching applications requiring a low forward voltage drop.

MARKING CODE: CT4

MAXIMUM RATINGS: (T _A =25°C)	SYMBOL		UNITS
Peak Repetitive Reverse Voltage	V_{RRM}	40	V
Continuous Forward Current	I _F	200	mA
Peak Repetitive Forward Current	I _{FRM}	300	mA
Peak Forward Surge Current, tp=10ms	I _{FSM}	600	mA
Power Dissipation (Note 1)	P_{D}	350	mW
Power Dissipation (Note 2)	P_{D}	300	mW
Power Dissipation (Note 3)	P_{D}	150	mW
Operating and Storage Junction Temperature	T _J , T _{stg}	-65 to +150	°C
Thermal Resistance (Note 1)	Θ_{JA}	357	°C/W

ELECTRICAL CHARACTERISTICS PER DIODE: (TA=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{R}	V _R =25V		100	500	nA
BV_R	I _R =100μA	40	55		V
V_{F}	I _F =100μA		0.24	0.26	V
V_{F}	I _F =500μA		0.29	0.31	V
V_{F}	I _F =1.0mA		0.31	0.33	V
V_{F}	I _F =50mA		0.54	0.60	V
V_{F}	I _F =100mA		0.67	0.75	V
C_{J}	V _R =1.0V, f=1.0MHz			10	pF
t _{rr}	$I_F=I_R=10$ mA, $I_{rr}=1.0$ mA, $R_L=100$ Ω			5.0	ns

Notes: (1) Ceramic or aluminum core PC Board with copper mounting pad area of 4.0mm² (2) FR-4 Epoxy PC Board with copper mounting pad area of 4.0mm² (3) FR-4 Epoxy PC Board with copper mounting pad area of 1.4mm²

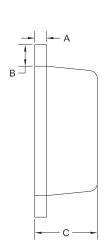
R5 (1-July 2015)

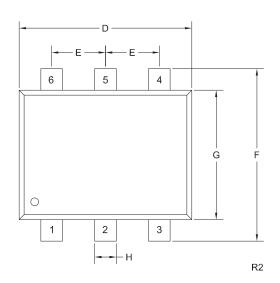
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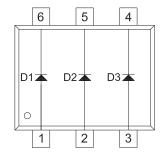


SOT-563 CASE - MECHANICAL OUTLINE





PIN CONFIGURATION



DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
Α	0.0027	0.007	0.07	0.18			
В	0.008		0.20				
С	0.017	0.024	0.45	0.60			
D	0.059	0.067	1.50	1.70			
E	0.020		0.50				
F	0.059	0.067	1.50	1.70			
G	0.043	0.051	1.10	1.30			
Н	0.006	0.012	0.15	0.30			
SOT-563 (REV: R2)							

LEAD CODE:

- 1) Anode D1
- 2) Anode D2
- 3) Anode D3
- 4) Cathode D3
- 5) Cathode D2
- 6) Cathode D1

MARKING CODE: CT4

R5 (1-July 2015)

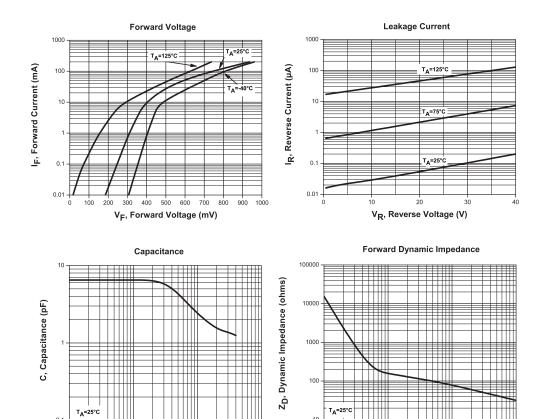
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TYPICAL ELECTRICAL CHARACTERISTICS



R5 (1-July 2015)

I_F, Forward Current (mA)

V_R, Reverse Voltage (V)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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